

6MBI75S-120

IGBT Modules

IGBT MODULE (S series) 1200V / 75A 6 in one-package

■ Features

- Compact package
- P.C.board mount
- Low $V_{CE(sat)}$

■ Applications

- Inverter for motor drive
- AC and DC servo drive amplifier
- Uninterruptible power supply
- Industrial machines, such as welding machines

■ Maximum ratings and characteristics

● Absolute maximum ratings ($T_c=25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Rating	Unit	
Collector-Emitter voltage	V_{CES}	1200	V	
Gate-Emitter voltage	V_{GES}	± 20	V	
Collector current	Continuous	$T_c=25^\circ\text{C}$	100	A
		$T_c=80^\circ\text{C}$	75	
	1ms	$T_c=25^\circ\text{C}$	200	A
		$T_c=80^\circ\text{C}$	150	
		-Ic	75	A
	1ms	-Ic pulse	150	A
Max. power dissipation (1 device)	P_c	520	W	
Operating temperature	T_j	+150	$^\circ\text{C}$	
Storage temperature	T_{stg}	-40 to +125	$^\circ\text{C}$	
Isolation voltage	V_{is}	AC 2500 (1min.)	V	
Screw torque	Mounting *1	3.5	N·m	

*1 : Recommendable value : 2.5 to 3.5 N·m (M5)

● Electrical characteristics ($T_j=25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Characteristics			Conditions	Unit	
		Min.	Typ.	Max.			
Zero gate voltage collector current	I_{CES}	-	-	1.0	$V_{GE}=0\text{V}$, $V_{CE}=1200\text{V}$	mA	
Gate-Emitter leakage current	I_{GES}	-	-	0.2	$V_{CE}=0\text{V}$, $V_{GE}=\pm 20\text{V}$	μA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	5.5	7.2	8.5	$V_{CE}=20\text{V}$, $I_c=75\text{mA}$	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	2.3	2.6	$T_j=25^\circ\text{C}$	$V_{GE}=15\text{V}$, $I_c=75\text{A}$	V
		-	2.8	-	$T_j=125^\circ\text{C}$		
Input capacitance	C_{ies}	-	9000	-	$V_{GE}=0\text{V}$	pF	
Output capacitance	C_{oes}	-	1875	-	$V_{CE}=10\text{V}$		
Reverse transfer capacitance	C_{res}	-	1650	-	$f=1\text{MHz}$		
Turn-on time	t_{on}	-	0.35	1.2	$V_{CC}=600\text{V}$ $I_c=75\text{A}$ $V_{GE}=\pm 15\text{V}$ $R_G=16\Omega$	μs	
	t_r	-	0.25	0.6			
	$t_{r(i)}$	-	0.1	-			
Turn-off time	t_{off}	-	0.45	1.0			
	t_f	-	0.08	0.3			
Diode forward on voltage	V_F	-	2.5	3.3	$T_j=25^\circ\text{C}$	$I_F=75\text{A}$, $V_{GE}=0\text{V}$	V
		-	2.0	-	$T_j=125^\circ\text{C}$		
Reverse recovery time	t_{rr}	-	-	0.35	$I_F=75\text{A}$	μs	

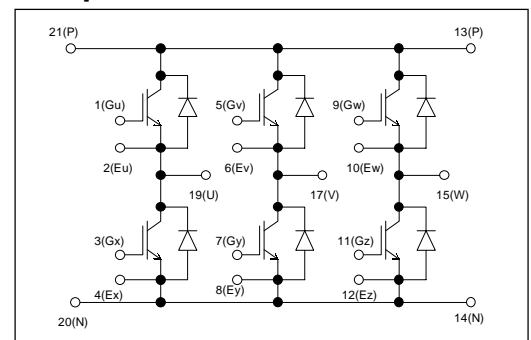
● Thermal resistance characteristics

Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Thermal resistance	$R_{th(j-c)}$	-	-	0.24	IGBT	$^\circ\text{C/W}$
	$R_{th(j-c)}$	-	-	0.50	FWD	$^\circ\text{C/W}$
	$R_{th(c-f)*2}$	-	0.05	-	the base to cooling fin	$^\circ\text{C/W}$

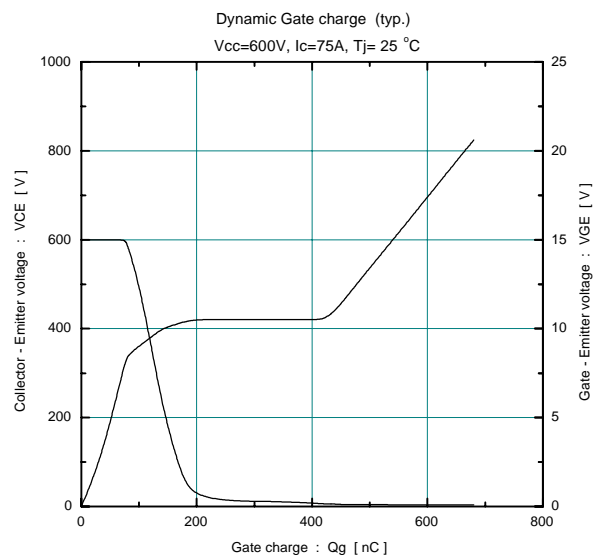
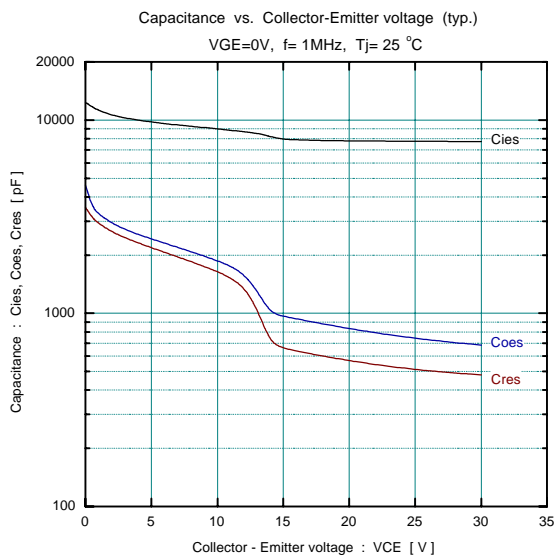
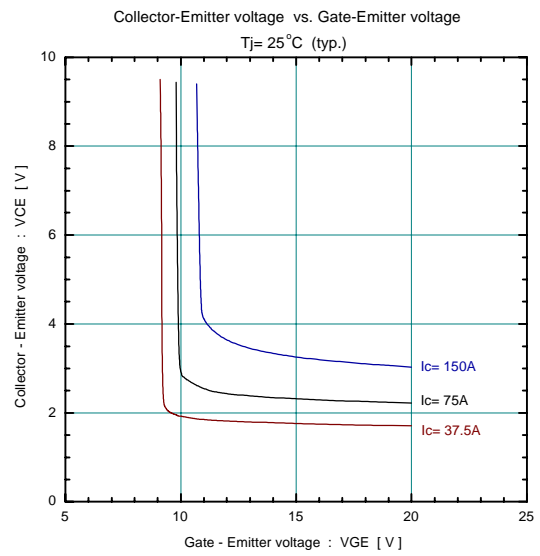
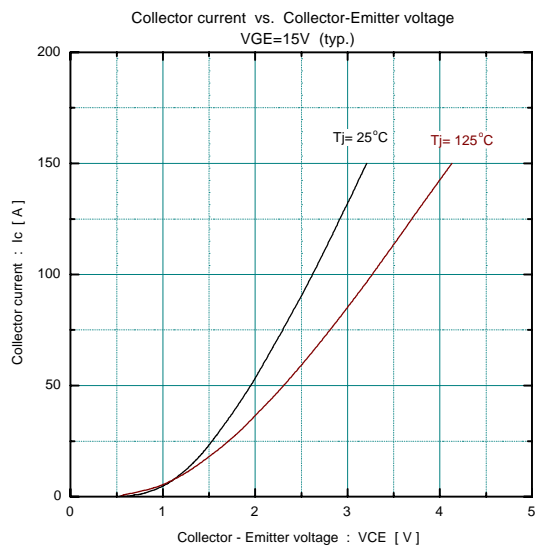
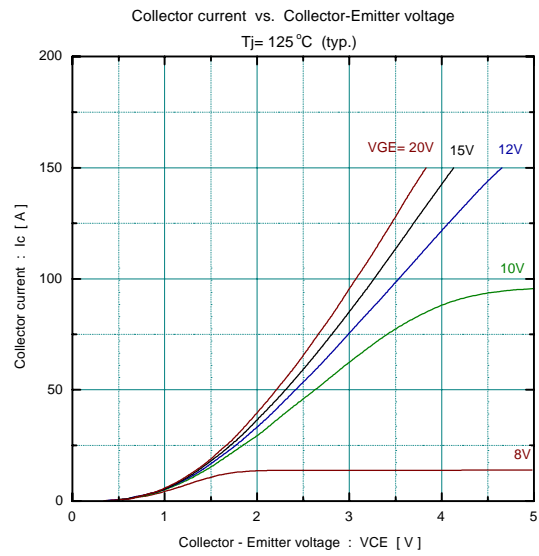
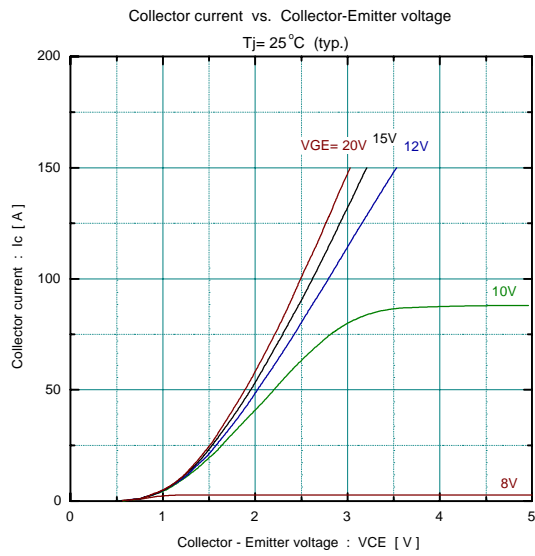
*2 : This is the value which is defined mounting on the additional cooling fin with thermal compound

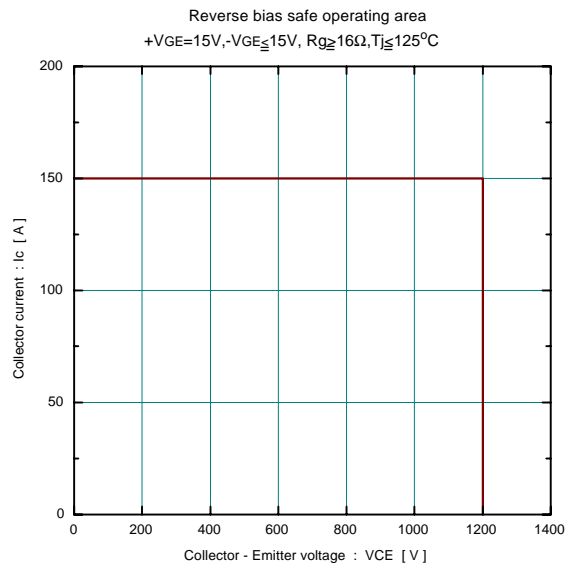
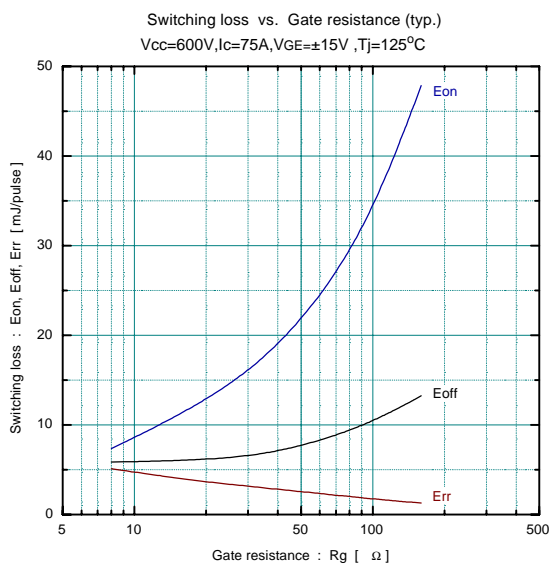
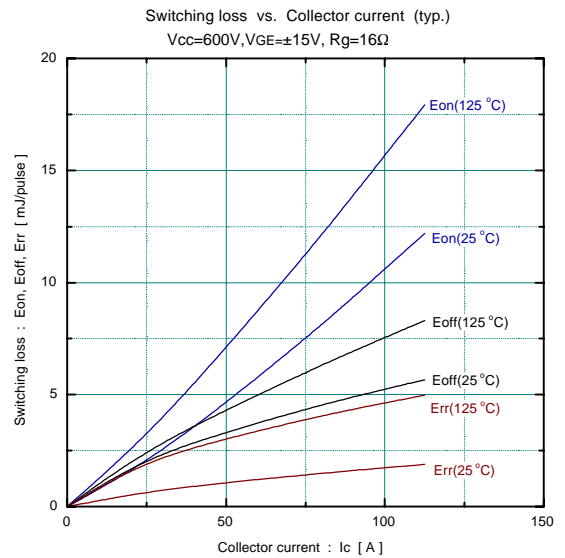
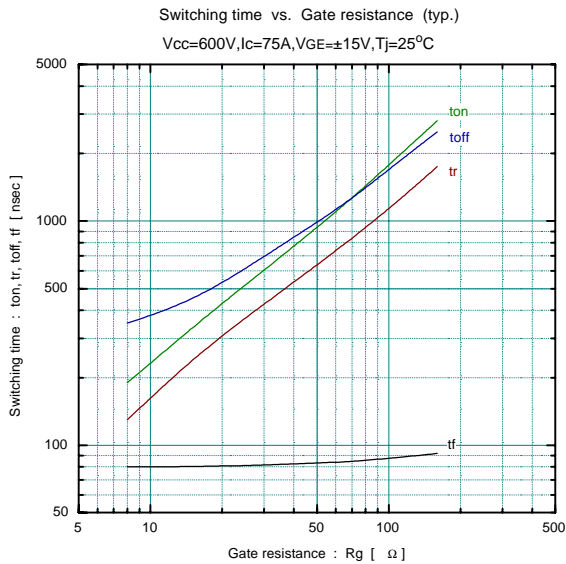
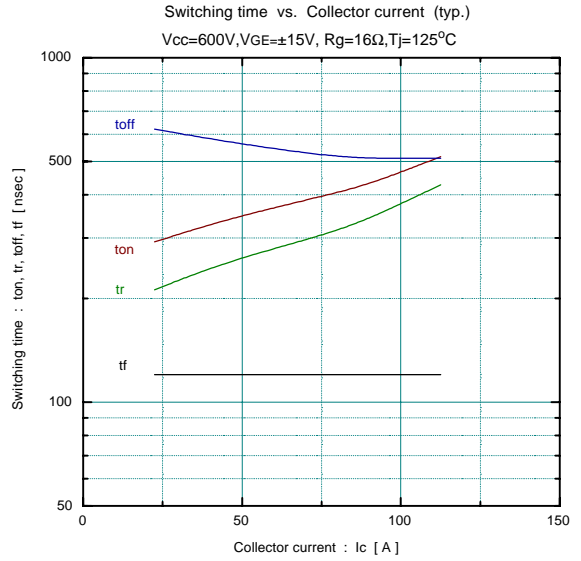
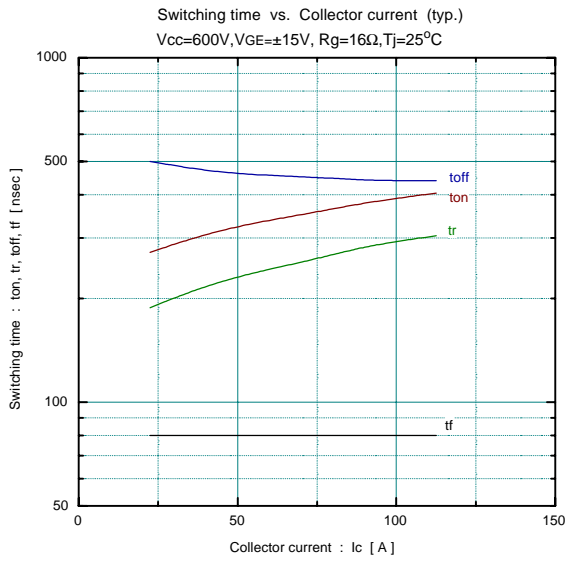


■ Equivalent Circuit Schematic

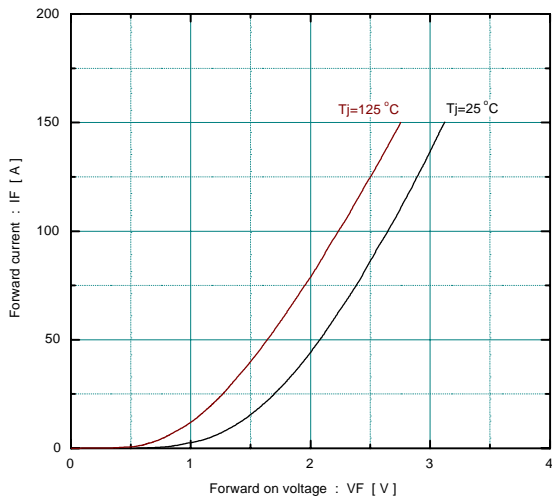


■ Characteristics

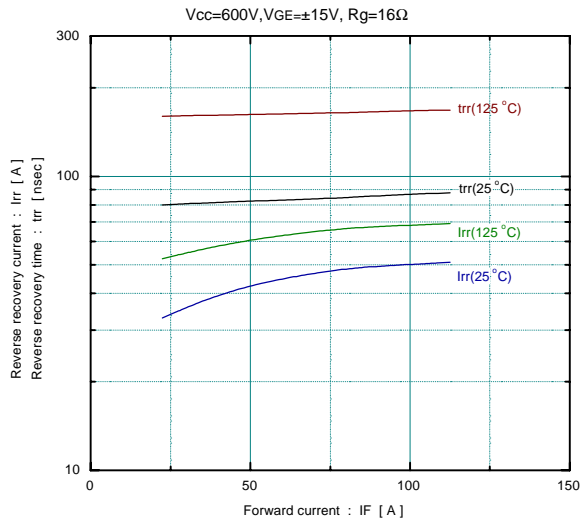




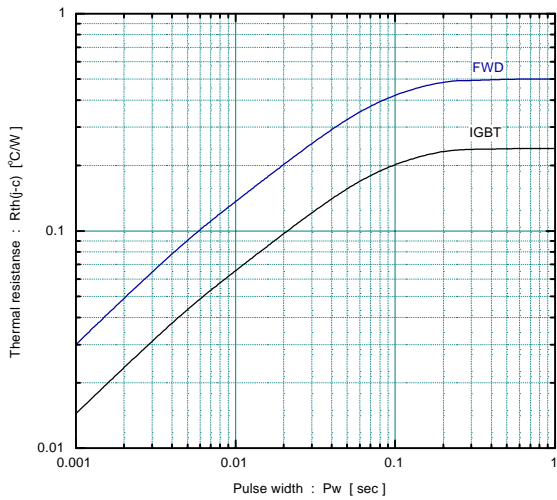
Forward current vs. Forward on voltage (typ.)



Reverse recovery characteristics (typ.)



Transient thermal resistance



■ Outline Drawings, mm

